

# **Product Specification PE4244**

# SPDT UltraCMOS™ RF Switch

#### **Features**

- Single +3.0-volt Power Supply
- Low Insertion loss: 0.60 dB up to 2.0 GHz
- High isolation of 39 dB at 1.0 GHz, 29 dB at 2.0 GHz
- Typical 1 dB compression of +27 dBm
- Single-pin CMOS logic control
- Packaged in 8-lead MSOP

# **Product Description**

The PE4244 UltraCMOS™ RF Switch is designed to cover a broad range of applications from DC to 3.0 GHz. This switch integrates on-board CMOS control logic with a low voltage CMOS compatible control input. Using a +3-volt nominal power supply voltage, a 1 dB compression point of +27 dBm can be achieved. The PE4244 also exhibits excellent isolation of 39 dB at 1.0 GHz and is offered in a small 8-lead MSOP package.

The PE4244 UltraCMOS™ RF Switch is manufactured in Peregrine's patented Ultra Thin Silicon (UTSi®) CMOS process, offering the performance of GaAs with the economy and integration of conventional CMOS.

Figure 1. Functional Diagram

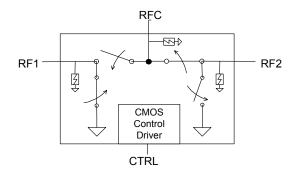


Figure 2. Package Type 8-lead MSOP



Table 1. Electrical Specifications @ +25 °C,  $V_{DD}$  = 3 V ( $Z_{S}$  =  $Z_{L}$  = 50  $\Omega$ )

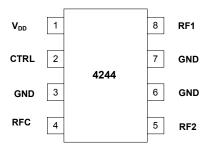
| Parameter                        | Conditions                        | Minimum | Typical | Maximum | Units     |
|----------------------------------|-----------------------------------|---------|---------|---------|-----------|
| Operation Frequency <sup>1</sup> |                                   | DC      |         | 3000    | MHz       |
| Incortion Logo                   | 1000 MHz                          |         | 0.60    | 0.75    | dB        |
| Insertion Loss                   | 2000 MHz                          |         | 0.60    | 0.75    | dB        |
| Indiation REC to RE1/RE2         | 1000 MHz                          | 37      | 39      |         | dB        |
| Isolation – RFC to RF1/RF2       | 2000 MHz                          | 27      | 29      |         | dB        |
| Isolation – RF1 to RF2           | 1000 MHz                          | 34      | 36      |         | dB        |
|                                  | 2000 MHz                          | 26      | 28      |         | dB        |
| Detum Lees                       | 1000 MHz                          | 19      | 20      |         | dB        |
| Return Loss                      | 2000 MHz                          | 22      | 25      |         | dB        |
| 'ON' Switching Time              | CTRL to 0.1 dB final value, 2 GHz |         | 200     |         | ns        |
| 'OFF' Switching Time             | CTRL to 25 dB isolation, 2 GHz    |         | 90      |         | ns        |
| Video Feedthrough <sup>2</sup>   |                                   |         | 15      |         | $mV_{pp}$ |
| Input 1 dB Compression           | 2000 MHz                          | 26      | 27      |         | dBm       |
| Input IP3                        | 2000 MHz, 14dBm                   | 43      | 45      |         | dBm       |

Notes: 1. Device linearity will begin to degrade below 10 MHz.

> 2. The DC transient at the output of any port of the switch when the control voltage is switched from Low to High or High to Low in a 50  $\Omega$ test set-up, measured with 1ns risetime pulses and 500 MHz bandwidth.



Figure 3. Pin Configuration (Top View)



**Table 2. Pin Descriptions** 

| Pin<br>No. | Pin<br>Name     | Description  |
|------------|-----------------|--|
| 1          | V <sub>DD</sub> | Nominal 3 V supply connection. A by-<br>pass capacitor (100 pF) to the ground<br>plane should be placed as close as pos- |
| 2          | CTRL            | CMOS logic level:  |
|            |                 | High = RFC to RF1 signal path  |
| 3          | GND             | Ground connection. Traces should be physically short and connected to  |
| 4          | RFC             | Common RF port for switch (Note 1)   |
| 5          | RF2             | RF2 port (Note 1)  |
| 6          | GND             | Ground Connection. Traces should be physically short and connected to  |
| 7          | GND             | Ground Connection. Traces should be physically short and connected to  |
| 8          | RF1             | RF1 port (Note 1)  |

Note 1: All RF pins must be DC blocked with an external series capacitor or held at 0  $V_{\text{DC}}$ .

**Table 3. Absolute Maximum Ratings** 

| Symbol          | Parameter/Conditions      | Min  | Max               | Units |
|-----------------|---------------------------|------|-------------------|-------|
| $V_{DD}$        | Power supply voltage      | -0.3 | 4.0               | V     |
| Vı              | Voltage on any input      | -0.3 | V <sub>DD</sub> + | V     |
| T <sub>ST</sub> | Storage temperature range | -65  | 150               | °C    |
| T <sub>OP</sub> | Operating temperature     | -40  | 85                | °C    |
| P <sub>IN</sub> | Input power (50Ω)         |      | 30                | dBm   |
| $V_{ESD}$       | ESD voltage (Human Body   |      | 1500              | V     |

Absolute Maximum Ratings are those values listed in the above table. Exceeding these values may cause permanent device damage. Functional operation should be restricted to the limits in the DC Electrical Specifications table. Exposure to absolute maximum ratings for extended periods may affect device reliability.

**Table 4. DC Electrical Specifications** 

| Parameter                            | Min          | Тур | Max          | Units |
|--------------------------------------|--------------|-----|--------------|-------|
| V <sub>DD</sub> Power Supply Voltage | 2.7          | 3.0 | 3.3          | V     |
| I <sub>DD</sub> Power Supply Current |              | 250 | 500          | nA    |
| $V_{DD} = 3V, V_{CNTL} = 3V$         |              |     |              |       |
| Control Voltage High                 | $0.7xV_{DD}$ |     |              | V     |
| Control Voltage Low                  |              |     | $0.3xV_{DD}$ | V     |

# **Electrostatic Discharge (ESD) Precautions**

When handling this UltraCMOS™ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating.

### **Latch-Up Avoidance**

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

**Table 5. Control Logic Truth Table** 

| Control Voltage  | Signal Path |  |
|------------------|-------------|--|
| CTRL = CMOS High | RFC to RF1  |  |
| CTRL = CMOS Low  | RFC to RF2  |  |



## **Evaluation Kit**

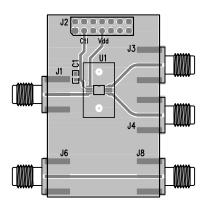
The SPDT Switch Evaluation Kit board was designed to ease customer evaluation of the PE4244 SPDT switch. The RF common port is connected through a 50  $\Omega$  transmission line to the top left SMA connector, J1. Port 1 and Port 2 are connected through 50  $\Omega$  transmission lines to the top two SMA connectors on the right side of the board, J3 and J4. A through transmission line connects SMA connectors J6 and J8. This transmission line can be used to estimate the loss of the PCB over the environmental conditions being evaluated.

The board is constructed of a two metal layer FR4 material with a total thickness of 0.031". The bottom layer provides ground for the RF transmission lines. The transmission lines were designed using a coplanar waveguide with ground plane model using a trace width of 0.030", trace gaps of 0.007", dielectric thickness of 0.028", metal thickness of 0.0014" and  $\varepsilon_r$  of 4.4.

J2 provides a means for controlling DC and digital inputs to the device. Starting from the lower left pin, the second pin to the right (J2-3) is connected to the device CTRL input. The fourth pin to the right (J2-7) is connected to the device V<sub>DD</sub> input. A decoupling capacitor (100 pF) is provided on both CTRL and V<sub>DD</sub> traces. It is the responsibility of the customer to determine proper supply decoupling for their design application. Removing these components from the evaluation board has not been shown to degrade RF performance.

Figure 4. Evaluation Board Layout

Peregrine specification 101/0037



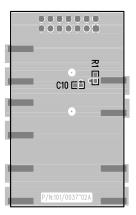


Figure 5. Evaluation Board Schematic Peregrine specification 101/0147

R1 1 M Ohm



# Typical Performance Data @ -40 °C to 85 °C (Unless otherwise noted)

Figure 6. Insertion Loss - RFC to RF1

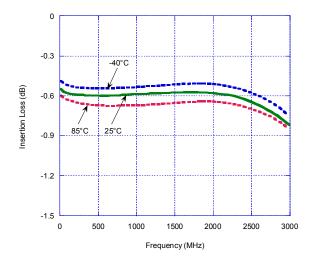


Figure 7. Input 1 dB Compression Point & IIP3

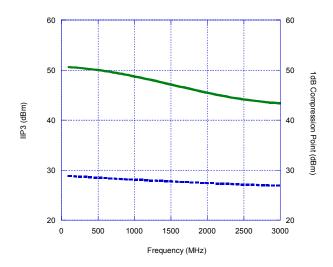


Figure 8. Insertion Loss – RFC to RF2

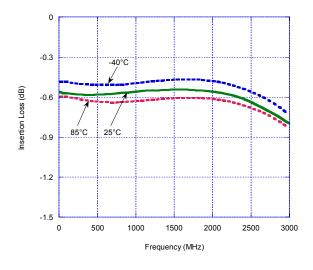
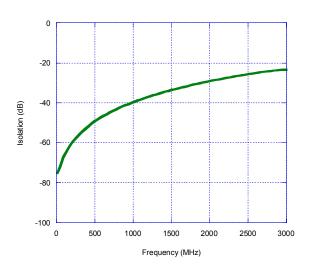


Figure 9. Isolation - RFC to RF1





# Typical Performance Data @ -40 °C to 85 °C (Unless otherwise noted)

Figure 10. Isolation – RFC to RF2

0 -20 -40 Isolation (dB) -60 -80 1000 2000 2500 3000 Frequency (MHz)

Figure 11. Isolation - RF1 to RF2, RF2 to RF1

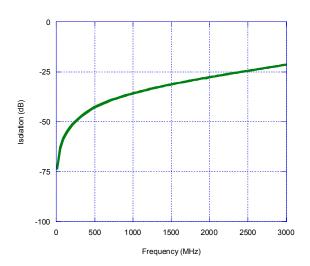


Figure 12. Return Loss – RFC to RF1, RF2

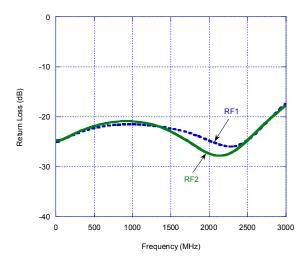
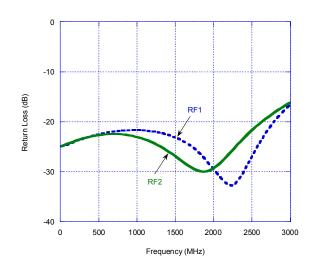


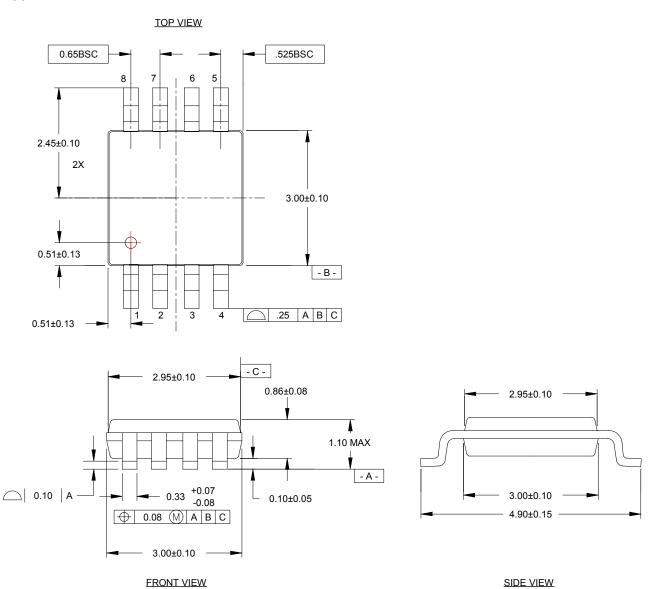
Figure 13. Return Loss - RF1, RF2





# Figure 14. Package Drawing

8-lead MSOP



**Table 6. Ordering Information** 

| Order Code | Part Marking | Description          | Package           | Shipping Method  |
|------------|--------------|----------------------|-------------------|------------------|
| 4244-01    | 4244         | PE4244-08MSOP-50A    | 8-lead MSOP       | 50 units / Tube  |
| 4244-02    | 4244         | PE4244-08MSOP-2000C  | 8-lead MSOP       | 2000 units / T&R |
| 4244-00    | PE4244-EK    | PE4244-08MSOP-EK     | Evaluation Kit    | 1 / Box          |
| 4244-51    | 4244         | PE4244G-08MSOP-50A   | Green 8-lead MSOP | 50 units / Tube  |
| 4244-52    | 4244         | PE4244G-08MSOP-2000C | Green 8-lead MSOP | 2000 units / T&R |



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#### Data Sheet Identification

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